PRELIMINARY DATA SHEET



NPN SILICON GERMANIUM RF TRANSISTOR NESG270034

NPN SIGE RF TRANSISTOR FOR MEDIUM OUTPUT POWER AMPLIFICATION (2 W) 3-PIN POWER MINIMOLD (34 PKG)

FEATURES

• This product is suitable for medium output power (2 W) amplification

 $P_{out} = 33.5 \ dBm$ TYP. @ $V_{CE} = 6 \ V, \ P_{in} = 20 \ dBm, \ f = 460 \ MHz$

 $P_{out} = 31.5 \text{ dBm TYP.}$ @ $V_{CE} = 6 \text{ V}$, $P_{in} = 20 \text{ dBm}$, f = 900 MHz

- Using UHS2-HV process (SiGe technology), VcBo (ABSOLUTE MAXIMUM RATINGS) = 25 V
- 3-pin power minimold (34 PKG)

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG270034	NESG270034-AZ	3-pin power minimold (34 PKG) (Pb-Free) Note1, 2	25 pcs (Non reel)	Magazine case
NESG270034-T1	NESG270034-T1-AZ		1 kpcs/reel	12 mm wide embossed taping Pin 2 (Emitter) face the perforation side of the tape

- **Notes 1.** Contains Lead in the part except the electrode terminals.
 - 2. With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact your nearby sales office.

Remark To order evaluation samples, contact your nearby sales office. Unit sample quantity is 25 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	25	٧
Collector to Emitter Voltage	Vceo	9.2	٧
Emitter to Base Voltage	VEBO	2.8	٧
Collector Current	lc	750	mA
Total Power Dissipation	P _{tot} Note	1.9	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	−65 to +150	°C

Note Mounted on 34.2 cm² × 0.8 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Document No. PU10577EJ01V0DS (1st edition) Date Published September 2005 CP(K)

THERMAL RESISTANCE (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Termal Resistance from Junction to Ambient Note	Rth _{j-a}	65	°C/W

Note Mounted on $34.2 \text{ cm}^2 \times 0.8 \text{ mm}$ (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE (TA = +25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Collector to Emitter Voltage	Vce	ı	6.0	7.2	٧
Collector Current	lc	-	600	750	mA
Input Power Note	Pin	-	20	23	dBm

Note Input power under conditions of $V_{\text{CE}} \le 6.0 \text{ V}, \, f = 460 \text{ MHz}$

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	VcB = 9.2 V, IE = 0 mA	-	-	1	μА
Emitter Cut-off Current	ІЕВО	Veb = 1.0 V, Ic = 0 mA	-	-	1	μА
DC Current Gain	hfe Note	VcE = 3 V, Ic = 100 mA	80	120	180	-
RF Characteristics					•	
Linner Gain (1)	G∟	VcE = 6 V, Ic (set) = 30 mA (RF OFF),	17.5	19.5	_	dB
		f = 460 MHz, P _{in} = 0 dBm				
Linner Gain (2)	G∟	VcE = 6 V, Ic (set) = 30 mA (RF OFF),	_	15	_	dB
		$f = 900 \text{ MHz}, P_{in} = 0 \text{ dBm}$				
Output Power (1)	Pout	$V_{CE} = 6 \text{ V}, \text{ Ic (set)} = 30 \text{ mA (RF OFF)},$	31.5	33.5	_	dBm
		f = 460 MHz, P _{in} = 20 dBm				
Output Power (2)	Pout	$V_{CE} = 6 \text{ V, Ic}$ (set) = 30 mA (RF OFF),	_	31.5	_	dBm
		f = 900 MHz, P _{in} = 20 dBm				
Collector Efficiency (1)	ηс	$V_{CE} = 6 \text{ V, Ic}$ (set) = 30 mA (RF OFF),	_	60	_	%
		f = 460 MHz, P _{in} = 20 dBm				
Collector Efficiency (2)	ηс	$V_{CE} = 6 \text{ V, Ic}_{\text{(set)}} = 30 \text{ mA (RF OFF)},$	_	50	_	%
		f = 900 MHz, Pin = 25 dBm				

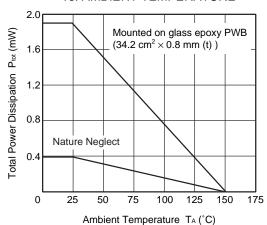
Note Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

hfe CLASSIFICATION

Rank	FB		
Marking	SQ		
h _{FE} Value	80 to 180		

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



Remark The graph indicates nominal characteristics.

S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

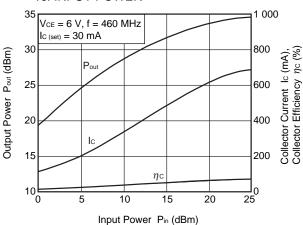
Click here to download S-parameters.

 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$

URL http://www.ncsd.necel.com/

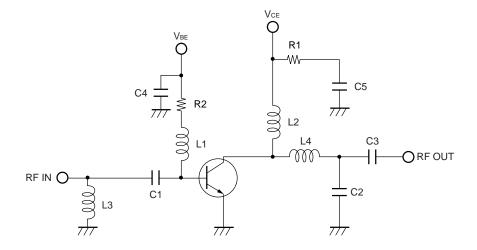
PA EVALUATION CIRCUIT TYPICAL CHARACTERISTICS





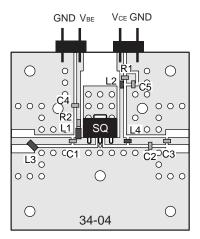
Remark The graph indicates nominal characteristics.

EVALUATION CIRCUIT (f = 460 MHz)



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

EVALUATION BOARD (f = 460 MHz)



Notes

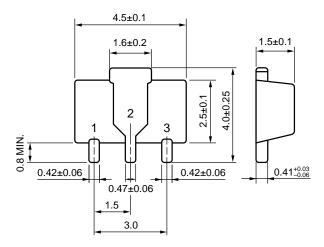
- 1. 38×38 mm, t = 0.8 mm double sided copper clad glass epoxy PWB.
- 2. Back side: GND pattern
- 3. Solder gold plated on pattern
- 4. o O: Through holes

COMPONENT LIST

Component	Maker	Value	Size (TYPE)	Purpose
C1	Murata	11 pF	1005	Input DC Block/Input RF Matching
C2	Murata	9.5 pF	1005	Input RF Matching
C3	Murata	39 pF	1005	Input DC Block/Output RF Matching
C4	Murata	10 000 pF	1005	RF GND
C5	Murata	10 000 pF	1005	RF GND
L1	Toko	390 nH	2012	RF Block/Input RF Matching
L2	Toko	47 nH	1608	RF Block/Output RF Matching
L3	Toko	5.6 nH	2012	Input RF Matching
L4	Toko	5.1 nH	1608	Output RF Matching
R1	SSM	15 Ω	1005	Improve Stability
R2	SSM	10 Ω	1005	Improve Stability

PACKAGE DIMENSIONS

3-PIN POWER MINIMOLD (34 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base

When the product(s) listed in this document is subject to any applicable import or export control laws and regulation of the authority having competent jurisdiction, such product(s) shall not be imported or exported without obtaining the import or export license.

- The information in this document is current as of September, 2005. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of
 third parties by or arising from the use of NEC semiconductor products listed in this document or any other
 liability arising from the use of such products. No license, express, implied or otherwise, is granted under any
 patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of customer's equipment shall be done under the full
 responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
 parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
 - "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation, NEC Compound Semiconductor Devices, Ltd. and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

M8E 00.4-0110

▶ For further information, please contact

NEC Compound Semiconductor Devices, Ltd. http://www.ncsd.necel.com/

E-mail: salesinfo@ml.ncsd.necel.com (sales and general)

techinfo@ml.ncsd.necel.com (technical)

Sales Division TEL: +81-44-435-1573 FAX: +81-44-435-1579

NEC Compound Semiconductor Devices Hong Kong Limited

E-mail: ncsd-hk@elhk.nec.com.hk (sales, technical and general)

Hong Kong Head Office TEL: +852-3107-7303 FAX: +852-3107-7309
Taipei Branch Office TEL: +886-2-8712-0478 FAX: +886-2-2545-3859
Korea Branch Office TEL: +82-2-558-2120 FAX: +82-2-558-5209

NEC Electronics (Europe) GmbH http://www.ee.nec.de/

TEL: +49-211-6503-0 FAX: +49-211-6503-1327

California Eastern Laboratories, Inc. http://www.cel.com/

TEL: +1-408-988-3500 FAX: +1-408-988-0279

0504



4590 Patrick Henry Drive Santa Clara, CA 95054-1817 Telephone: (408) 919-2500

Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)		on contained devices
Lead (Pb)	< 1000 PPM	-A -AZ Not Detected (*)	
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.